



PRODUCT DATA SHEET



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Datasheet

ces Sami

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.





ESD Protection Diode

Features

- 150Watts peak pulse power (tp = $8/20\mu$ s)
- SOD-323 package
- Bidirectional configurations
- Low clamping voltage
- Low leakage current
- Protection one data/power line to:
- IEC 61000-4-2 ±8kV contact ±15kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- **IEC** 61000-4-5 (Lightning) 10A (8/20μs)



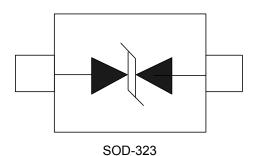
Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- SOD-323 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration





Absolute Maximum Rating

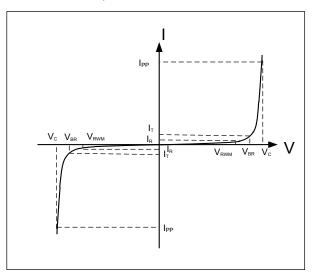
Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20μs)	P_{PP}	150	Watts
Peak Pulse Current (t _p =8/20μs) (note1)	I_{pp}	10	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$ m V_{ESD}$	15 8	
Lead Soldering Temperature	${ m T_L}$	260(10seconds)	$^{\circ}$
Junction Temperature	-55 to + 125		$^{\circ}$ C
Storage Temperature	$T_{ m stg}$	-55 to + 125	°C

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	5.8			V
Reverse Leakage Current	I_R	V _{RWM} =5V,T=25°C			1	μΑ
Peak Pulse Current	I_{PP}	tp =8/20μs			10	A
Clamping Voltage	$V_{\rm C}$	$I_{PP}=10A, t_p=8/20\mu s$			16	V
Junction Capacitance	C _j	$V_R = 0V, f = 1MHz$			100	pF

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ Ipp		
V _{RWM}	Working Peak Reverse Voltage		
IR	Maximum Reverse Leakage Current @ Vrwм		
V_{BR}	Breakdown Voltage @ IT		
Iт	Test Current		



Ver.1.0

Note:. $8/20\mu s$ pulse waveform.



Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

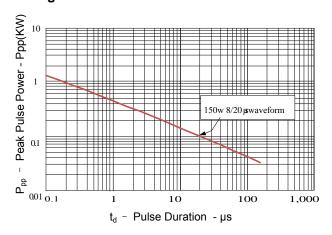


Figure 2: Power Derating Curve

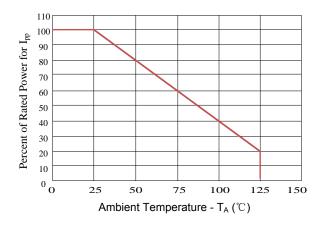


Figure3: Pulse Waveform

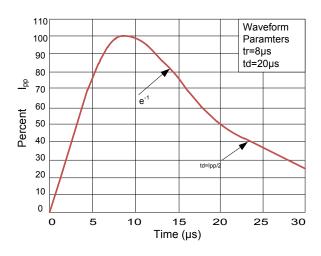
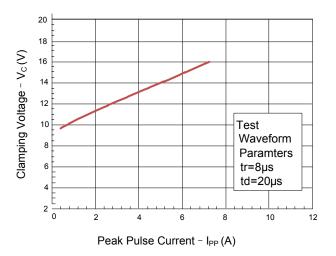
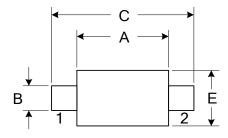


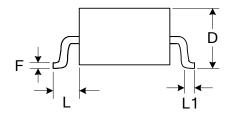
Figure 4: Clamping Voltage vs.lpp

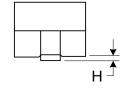




Outline Drawing - SOD323







DIMENSIONS					
SYMBOL	MILLIMETER		INCHES		
	MIN	MAX	MIN	MAX	
Α	1.600	1.800	0.063	0.071	
В	0.250	0.350	0.010	0.014	
С	2.500	2.700	0.098	0.106	
D		1.000		0.039	
E	1.200	1.400	0.047	0.055	
F	0.080	0.150	0.003	0.006	
L	0.475 REF		0.019REF		
L1	0.250	0.400	0.010	0.016	
Н	0.000	0.100	0.000	0.004	

Marking



Ordering information

Order code	Package	Base qty	Delivery mode
TESD05FB	SOD323	3000	Tape and reel



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